

# ZXCT1030

## High-side current monitor with comparator

### Description

The ZXCT1030 is a high side current sense monitor containing an internal reference and comparator with a non-latching output. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

### Features

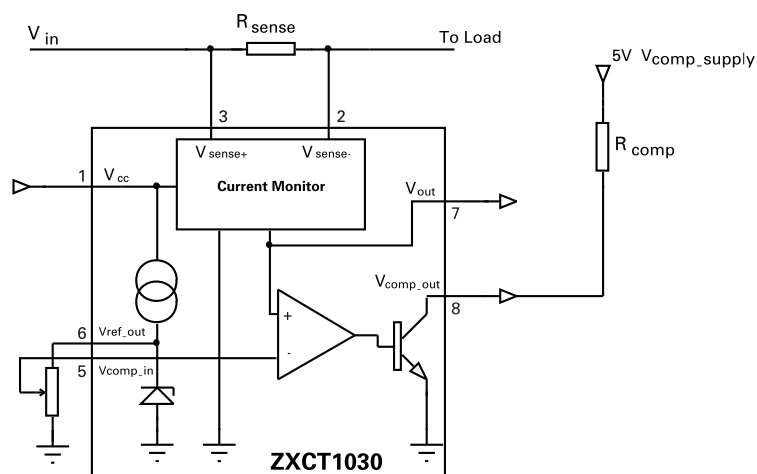
- Low cost, accurate high-side current sensing
- Output voltage scaling
- Up to 18V output
- 2.2V - 20V supply range
- 270 $\mu$ A quiescent current
- 1.5% typical accuracy
- SO8 package
- Voltage reference on chip
- Comparator on chip

The wide input voltage range of 20V down to as low as 2.2V make it suitable for a range of applications. Dynamics and supply current are optimized for the processing of fast pulses, associated with switch mode applications.

### Applications

- Battery chargers
- Electronic fuse
- DC motor control
- Over current monitor
- Power management
- Inrush current limiting

### Typical application circuit



### Ordering information

Device	Status	Package	Device marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXCT1030X8TA	Last time buy	MSOP8	ZXCT1030	7	12	1000
ZXCT1030N8TA	Preview	SO8	ZXCT1030	7	12	500

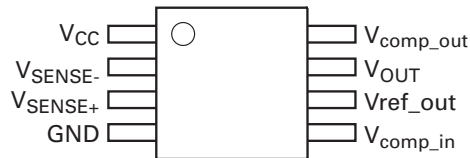
## Absolute maximum ratings

Voltage on any pin	-0.6V and $V_{CC} + 0.6V$
Operating temperature	-40 to 85°C
Storage temperature	-55 to 125°C
Package power dissipation	( $T_{amb} = 25^{\circ}C$ )
MSOP8	500mW

## Recommended operating conditions

Parameter	Min.	Max.	Unit
$V_{CC}$	2.2	20	V
$V_{SENSE+}$	2.2	$V_{CC}$	V
$V_{SENSE}^{(a)}$	10	500	mV
$V_{OUT}$	0	$V_{SENSE} - 1V$	V
$V_{comp\_in}$	0.005	10	V
$T_{amb}$	-40	85	°C

## Pin-out connections



Pin name	Function
$V_{CC}$	Supply voltage
$V_{SENSE-}$	Negative sense input
$V_{SENSE+}$	Positive sense input
GND	Ground
$V_{comp\_in}$	Comparator input, usually a ratio of the reference or other control signal
Vref_out	Reference output
$V_{OUT}$	Current monitor output voltage
$V_{comp\_out}$	Open collector comparator output

# ZXCT1030

**Electrical characteristics (ZXCT1030X8)** - Test conditions  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{IN} = V_{CC} = 15\text{V}$ ,  $R_{comp} = 10\text{k}\Omega$ ,  $V_{comp\_supply} = 5\text{V}$  unless otherwise stated.

Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
V <sub>CC</sub>	V <sub>CC</sub> range		2.2		20	V
V <sub>SENSE+</sub>	Sense+ range		2.2		V <sub>CC</sub>	
V <sub>OUT</sub>	Output voltage	V <sub>SENSE</sub> = 0V	0	2	10	mV
		V <sub>SENSE</sub> = 10mV	88	100	112	mV
		V <sub>SENSE</sub> = 30mV	284	300	316	mV
		V <sub>SENSE</sub> = 50mV	480	500	520	mV
		V <sub>SENSE</sub> = 100mV	970	1000	1030	mV
		V <sub>SENSE</sub> = 500mV	4500	5000	5500	mV
R <sub>OUT</sub>	Output resistance	V <sub>SENSE-</sub> = 15V, V <sub>OUT</sub> = 1V	1.2	1.5	1.8	kΩ
V <sub>OUT</sub> T <sub>C</sub>	V <sub>OUT</sub> temperature coefficient			30		ppm/°C
I <sub>CC</sub>	Supply current	V <sub>SENSE-</sub> = 15V	170	270	350	μA
I <sub>SENSE+</sub>	V <sub>SENSE+</sub> input current			48	90	μA
I <sub>SENSE-</sub>	V <sub>SENSE-</sub> input current	V <sub>SENSE-</sub> = 14.9V		70	220	nA
V <sub>CM(min)</sub> <sup>(b)</sup>	Minimum active common mode voltage	V <sub>CC</sub> = 15V V <sub>comp_supply</sub> = 5V V <sub>comp_in</sub> = V <sub>REF</sub> V <sub>SENSE</sub> = 10mV	2.8			V
A <sub>CC</sub>	Accuracy	V <sub>SENSE</sub> = 100mV	-3		3	%
Gain	V <sub>OUT</sub> / V <sub>SENSE</sub>	V <sub>SENSE</sub> = 100mV	9.7	10.0	10.3	
BW	Bandwidth	V <sub>SENSE</sub> = 10mVp-p		3		MHz
		V <sub>SENSE</sub> = 100mVp-p		6		MHz
Comparator						
V <sub>comp_in</sub>	Input voltage		0.005		10	V
V <sub>H</sub>	Hysteresis			15		mV
I <sub>B</sub>	Input bias		5	80	150	nA
T <sub>D</sub>	Propagation delay			100		ns
V <sub>OL</sub>	Output voltage low		30	150	200	mV
V <sub>OH</sub>	Output voltage high				V <sub>comp_supply</sub>	V
I <sub>OL</sub>	Output sink current	V <sub>OL</sub> = 0.4V	2			mA
I <sub>OH</sub>	Output high leakage current				1.0	μA
Voltage reference						
V <sub>ref</sub>		Reference current = +300μA to -5μA	1.200	1.240	1.280	V
delta V <sub>ref</sub>	Change in V <sub>ref</sub>	I <sub>source</sub> 5μA to I <sub>sink</sub> 300μA		10		mV
T <sub>C</sub>				30		ppm/°C
PSR	Supply rejection			0.01		%/V

**NOTES:**

(a)  $V_{SENSE} = (V_{SENSE+}) - (V_{SENSE-})$

(b) Level of  $V_{SENSE+}$  where comparator output defaults to 'off'.

# ZXCT1030

**Electrical characteristics (ZXCT1030N8)** - Test conditions  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{IN} = V_{CC} = 15\text{V}$ ,  $R_{comp} = 10\text{k}\Omega$ ,  $V_{comp\_supply} = 5\text{V}$  unless otherwise stated.

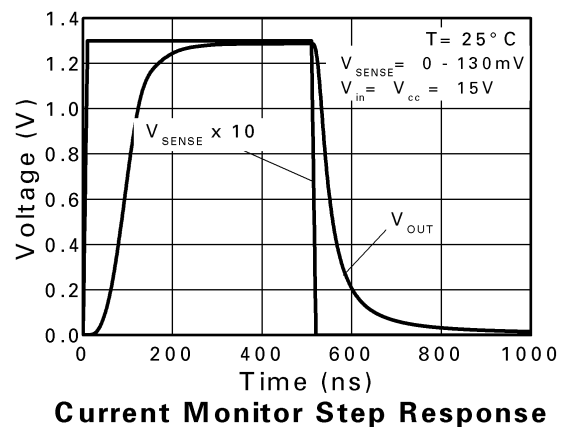
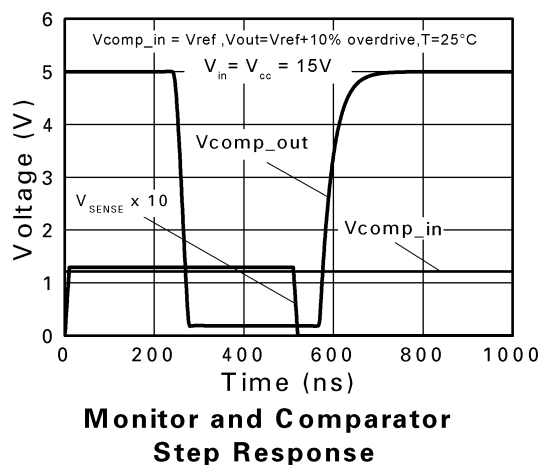
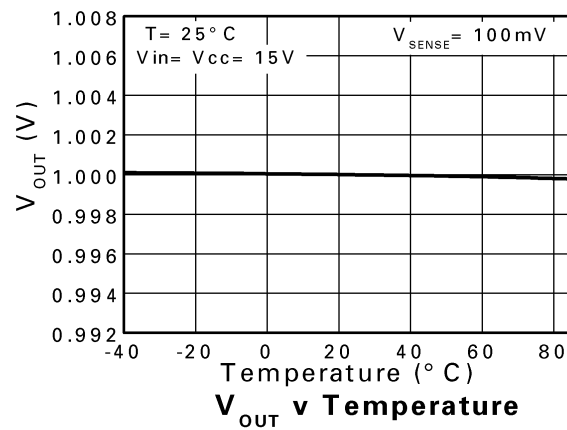
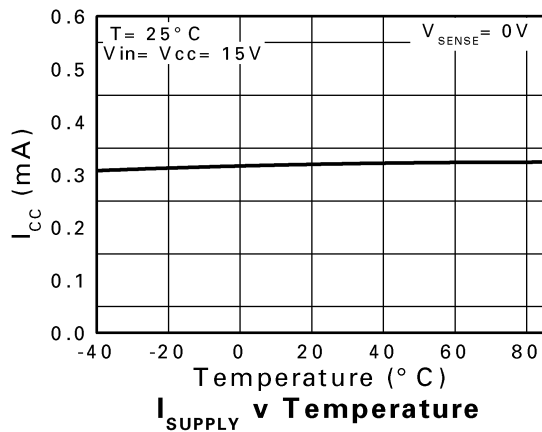
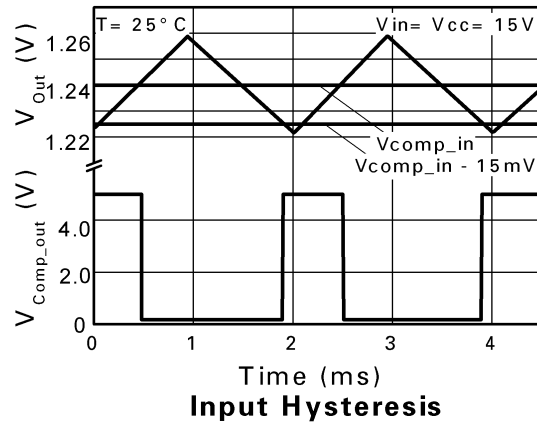
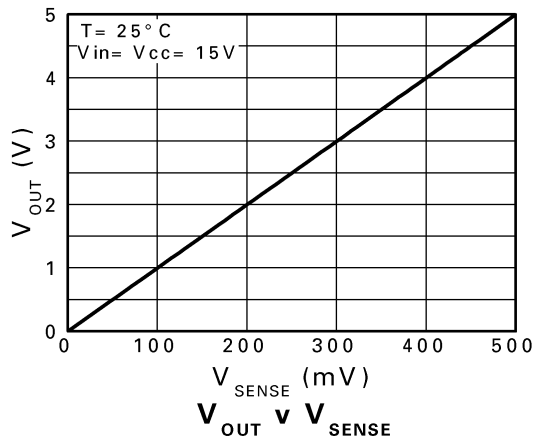
Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
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V <sub>OL</sub>	Output voltage low		30	150	200	mV
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T <sub>C</sub>				30		ppm/°C
PSR	Supply rejection			0.01		%/V

## NOTES:

(c)  $V_{SENSE} = (V_{SENSE+}) - (V_{SENSE-})$

(d) Level of  $V_{SENSE+}$  where comparator output defaults to 'off'.

## Typical characteristics



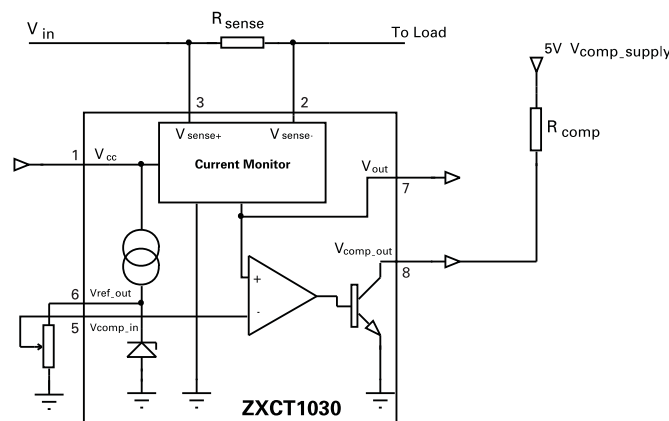
## Voltage output current monitor

Referring to the block diagram, the current monitor takes the small voltage developed across the sense resistor ( $V_{SENSE}$ ) and transfers it from the large common mode supply voltage to a ground-referenced signal with a gain of 10. The sense input common mode range is 2.2V to 20V. In this range, a linear output voltage is delivered.

## Reference

The bandgap reference allows the comparator to compare the translated  $V_{sense}$  with threshold value chosen by the user which can be any voltage from 0 to 1.24V, configured by two external resistors which forms  $V_{comp\_in}$ .

The output current which can be drawn from the comparator reference ( $I_{ref}$  source) is limited to 5 $\mu$ A, making potentiometers  $\geq 250k\Omega$  suitable for setting a threshold level. Where a lower potentiometer resistor value is used, an additional resistor value should be inserted between  $V_{ref}$  and  $V_{CC}$  to maintain sufficient current for the reference. (as shown in Figure 1).



**Figure 1: External resistor for reference level**

The voltage reference has a maximum current sink capability. This magnitude of current will be influenced by the value of  $R_1$  which is inserted between  $V_{ref}$  and  $V_{CC}$ . The value of current flowing through  $R_1$  can be expressed as:

$$I = (V_{CC} - V_{ref}) / R_1$$

## Comparator

The open collector output is active low and is asserted when  $V_{SENSE} \times 10 (V_{OUT}) > V_{comp\_in}$ .

It can be connected to any voltage rail up to  $V_{in}$  via a pull-up resistor. Suggest values for the resistor are in the range of 10-100k $\Omega$ .

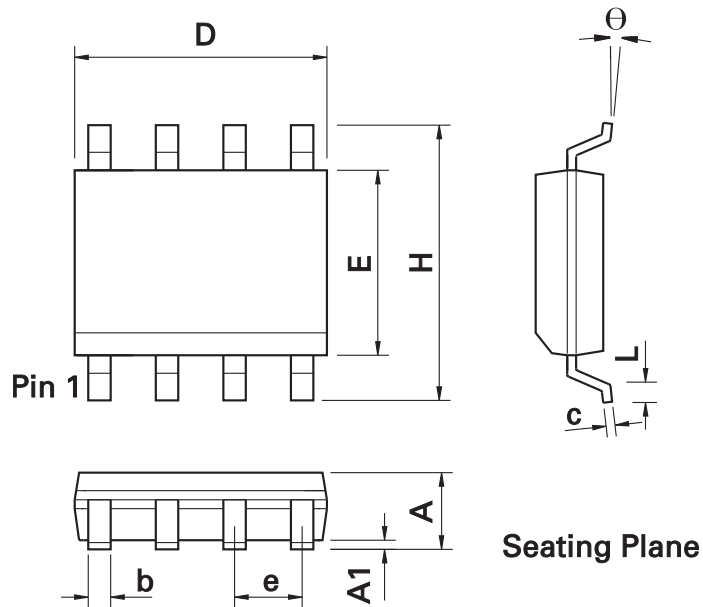
In the case where high load currents or a short circuit occurs, thus reducing the common mode signals ( $V_+$ ,  $V_-$ ) typically below 2.2V, the comparator will default to the asserted state. This can eliminate a closed loop system 'latch-up' condition, allowing the controller to remove the applied power.

## Stability

To ensure stable operation of the ZXCT1030, it is recommended a decoupling capacitor is placed across the  $V_{CC}$  and ground connections. A ceramic 10 $\mu$ F will be adequate.

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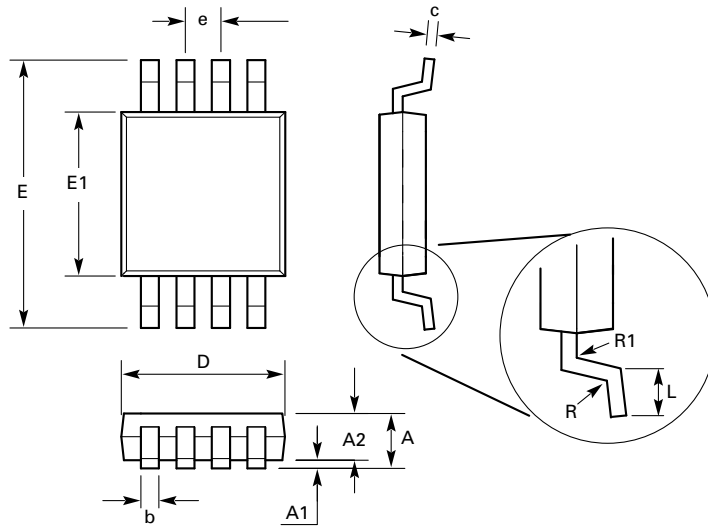
## Package outline - SO8



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.053	0.069	1.35	1.75	e	0.050 BSC		1.27 BSC	
A1	0.004	0.010	0.10	0.25	b	0.013	0.020	0.33	0.51
D	0.189	0.197	4.80	5.00	c	0.008	0.010	0.19	0.25
H	0.228	0.244	5.80	6.20	$\Theta$	0°	8°	0°	8°
E	0.150	0.157	3.80	4.00	h	0.010	0.020	0.25	0.50
L	0.016	0.050	0.40	1.27	-	-	-	-	-

**Note:** Controlling dimensions are in inches. Approximate dimensions are provided in millimeters

## Package outline - MSOP8



DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	-	1.10	-	0.0433
A1	0.05	0.15	0.002	0.006
A2	0.75	0.95	0.0295	0.0374
b	0.25	0.40	0.010	0.0157
c	0.13	0.23	0.005	0.009
D	2.90	3.10	0.114	0.122
E	4.90 BSC		0.193 BSC	
E1	2.90	3.10	0.114	0.122
e	0.65 BSC		0.025 BSC	
L	0.40	0.70	0.0157	0.0192
R	0.07	-	0.0027	-
R1	0.07	-	0.0027	-

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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